

# UF5400G THRU UF5408G

## Ultra Fast Glass Passivated Rectifier

Reverse Voltage - 50 to 1000 V

Forward Current - 3 A

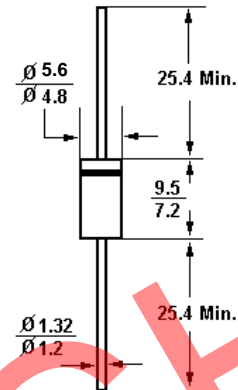
### Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Ultrafast recovery time for high efficiency
- High forward surge current capability
- Low reverse leakage

### Mechanical Data

- **Case:** Molded plastic body, JEDEC DO-201AD
- **Terminals:** Plated Axial leads, solderable per MIL-STD-750, method 2026
- **Polarity:** Color band denotes cathode end.
- **Mounting Position:** Any

DO-201AD



Dimensions in mm

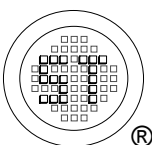
### Absolute Maximum Ratings and Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbols	UF5400G	UF5401G	UF5402G	UF5403G	UF5404G	UF5406G	UF5407G	UF5408G	Units	
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	200	300	400	600	800	1000	V	
Maximum RMS Voltage	$V_{RMS}$	35	70	140	210	280	420	560	700	V	
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	300	400	600	800	1000	V	
Maximum Average Forward Rectified Current 0.375" (9.5mm) Lead Length at $T_A = 55^\circ\text{C}$	$I_{F(AV)}$	3								A	
Peak Forward Surge Current 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC Method)	$I_{FSM}$	125								A	
Maximum Instantaneous Forward Voltage at 3 A	$V_F$	1			1.25		1.7			V	
Maximum Reverse Current $T_A = 25^\circ\text{C}$ at Rated Reverse Voltage $T_A = 100^\circ\text{C}$	$I_R$	5					150				$\mu\text{A}$
Maximum Reverse Recovery Time <sup>1)</sup>	$t_{rr}$	50					75				ns
Typical Junction Capacitance <sup>2)</sup>	$C_j$	75									pF
Operating Junction Temperature Range	$T_j$	- 65 to + 150									$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	- 65 to + 150									$^\circ\text{C}$

<sup>1)</sup> Reverse recovery condition  $I_F = 0.5\text{ A}$ ,  $I_R = 1\text{ A}$ ,  $I_{rr} = 0.25\text{ A}$ .

<sup>2)</sup> Measured at 1 MHz and applied reverse voltage of 4 V D.C.



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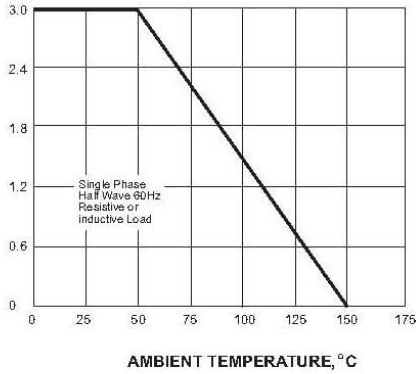


Dated : 18/03/2010 C Rev: 01

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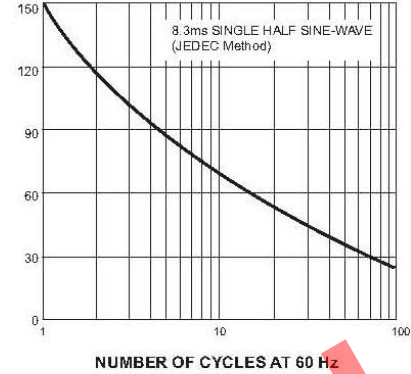
AVERAGE FORWARD RECTIFIED CURRENT, AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



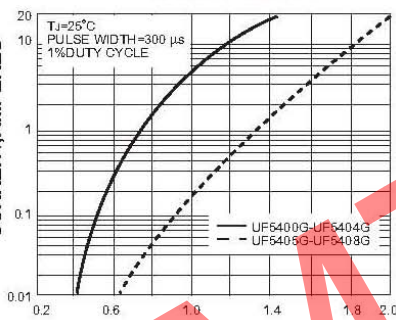
PEAK FORWARD SURGE CURRENT, AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



INSTANTANEOUS FORWARD CURRENT I<sub>F</sub>, AMPERES

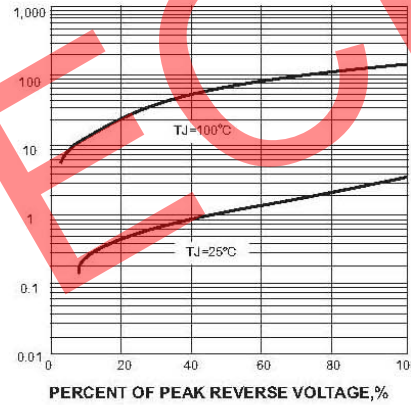
FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



INSTANTANEOUS FORWARD VOLTAGE, VOLTS

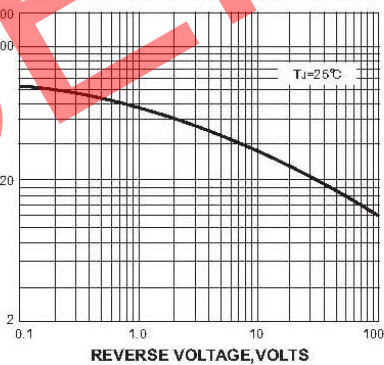
INSTANTANEOUS REVERSE CURRENT, MICROAMPERES

FIG. 4-TYPICAL REVERSE CHARACTERISTICS



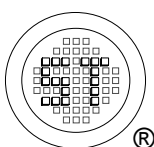
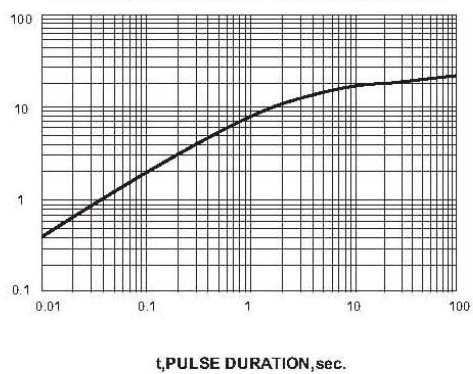
JUNCTION CAPACITANCE, pF

FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE, °C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



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